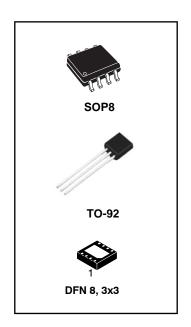


DESCRIPTION

The LM236 and LM336 are precision 5.0V regulator diodes. These voltage reference monolithic ICs operate like 5.0V zener diodes with a low temperature coefficient and a dynamic impedance of 0.6Ω . A third pin enables adjusting the reference voltage and the temperature coefficient.

Features

- Adjustable 4V to 6V
- Low temperature coefficient
- Wide operating current of 600 µA to 10 mA
- 0.6Ω dynamic impedance
- ± 1% initial tolerance available
- Guaranteed temperature stability
- Easily trimmed for minimum temperature drift
- Fast turn-on
- Three lead transistor package

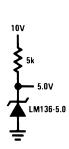


ORDERING INFORMATION

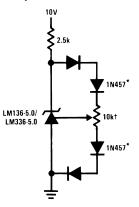
DEVICE	Package Type	MARKING	Packing	Packing Qty
LM236M-5.0/TR	SOP8L	LM236-5	Reel	2500pcs/reel
LM336M-5.0/TR	SOP8L	LM336-5	Reel	2500pcs/reel
LM236Z-5.0	TO-92	LM236-5	Tape	1000pcs/box
LM336Z-5.0	TO-92	LM336-5	Tape	1000pcs/box
LM236DQ-5.0/TR	DFN-8	LM236-5	Reel	2500pcs/reel
LM336DQ-5.0/TR	DFN-8	LM336-5	Reel	2500pcs/reel

Typical Applications

5.0V Reference

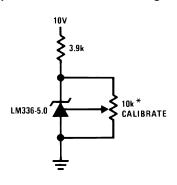


5.0V Reference with Minimum Temperature Coefficient



[†] Adjust to 5.00V

Trimmed 4V to 6V Reference with Temperature Coefficient Independent of Breakdown Voltage

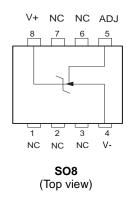


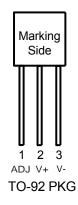
^{*} Does not affect temperature coefficient

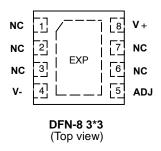
^{*} Any silicon signal diode



PIN CONNECTIONS







ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	LM336	Unit
I _R	Current Reverse Forward	15 10	mA
Toper	Operating Free-air Temperature Range	LM336-5.0: 0 to +70	°C
		LM236-5.0: -40 to +85	°C
T _{Stg}	Storage Temperature Range	-65 to +150	°C

SOP Package

Vapor Phase (60 sec.) 215°C Infrared (15 sec.) 220°C

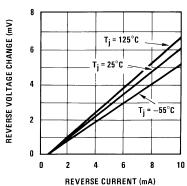
ELECTRICAL CHARACTERISTICS

Symbol	Parameter	LM236/LM336			Unit
Syllibol	Farameter	Min.	Тур.	Max.	Oiiit
V _R	Reference Breakdown Voltage T _{amb} = +25°C, I _R = 1mA	4.9	5.0	5.1	V
ΔV _R	Reverse Breakdown Voltage Change with Current $600\mu A \le I_R \le 10mA$ $T_{amb} = +25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	-	6	20	mV
Z _D	Reverse Dynamic Impedance ($I_R = 1mA$) $T_{amb} = +25^{\circ}C f=100Hz$ $T_{min.} \le T_{amb} \le T_{max.}$		0.6	2.0	Ω
K _{VT}	Temperature Stability ($V_R = 5.0V$, $I_R = 1mA$)	-	4	12	mV
K _{VH}	Long Term Stability ($T_{amb} = +25^{\circ}C \pm 0.1^{\circ}C$, $I_{R} = 1mA$)	-	20	-	ppm

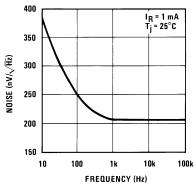


Typical Performance Characteristics

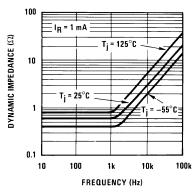




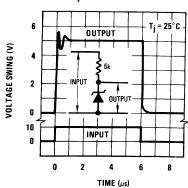
Zener Noise Voltage



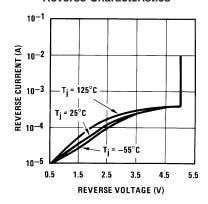
Dynamic Impedance



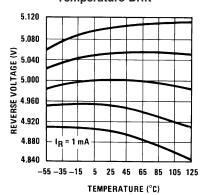
Response Time



Reverse Characteristics

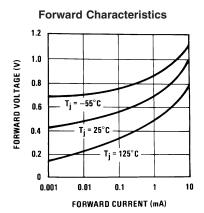


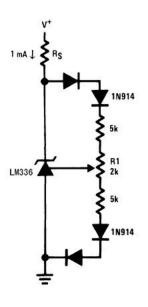
Temperature Drift





Typical Performance Characteristics (Continued)





Application Hints

The LMx36-5.0 series voltage references are much easier to use than ordinary zener diodes. Their low impedance and wide operating current range simplify biasing in almost any circuit. Further, either the breakdown voltage or the temperature coefficient can be adjusted to optimize circuit performance.

Figure 1 showsanLM336-5.0witha10kpotentiometerfor adjusting the reverse breakdown voltage. With the addition of R1 the breakdown voltage can be adjusted without affecting the temperature coefficient of the device. The adjustment range is usually sufficient to adjust for both the initial device tolerance and inaccuracies in buffer circuitry.

If minimum temperature coefficient is desired, four diodes can be added in series with the adjustment potentiometer as shown in *Figure 2*. When the device is adjusted to 5.00V the temperature coefficient is minimized. Almost any silicon signal diode can be used for this purpose such as a 1N914, 1N4148 or a 1N457. For proper temperature compensation the diodes should be in the same thermal environment as theLM336-5.0.Itisusuallysufficienttomountthediodes neartheLM336-5.0ontheprintedcircuitboard.Theabso-

lute resistance of the network is not critical and any value from 2k to 20k will work. Because of the wide adjustment range, fixed resistors should be connected in series with the pot to make pot setting less critical.

FIGURE 2. Temperature Coefficient Adjustment (Trim Range = ±0.5V Typical)

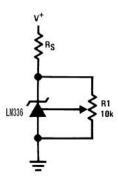
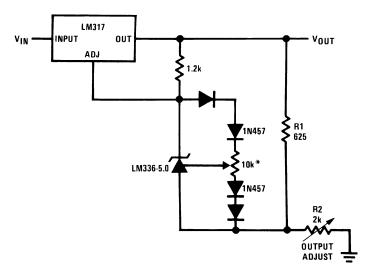


FIGURE1.LM336-5.0withPotforAdjustmentof Breakdown Voltage (Trim Range = ±1.0V Typical)

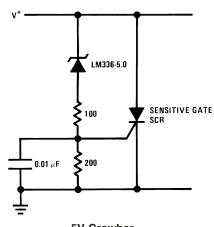


Typical Applications

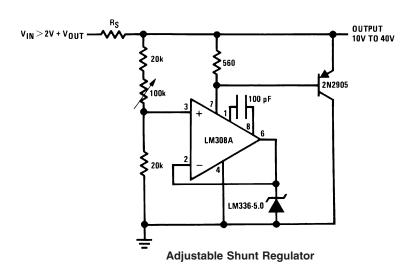


Precision Power Regulator with Low Temperature Coefficient

* Adjust for 6.25V across R1

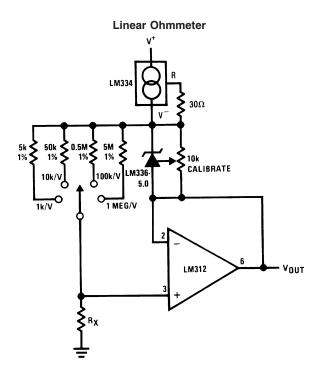


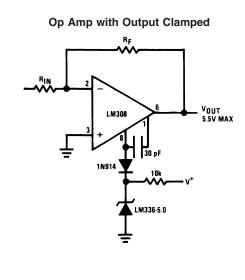
5V Crowbar



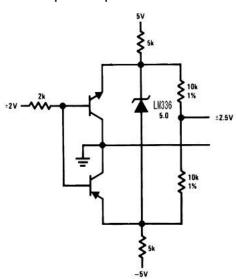


Typical Applications (Continued)

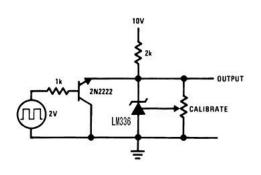




Bipolar Output Reference



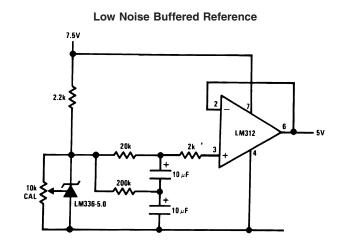
5.0V Square Wave Calibrator



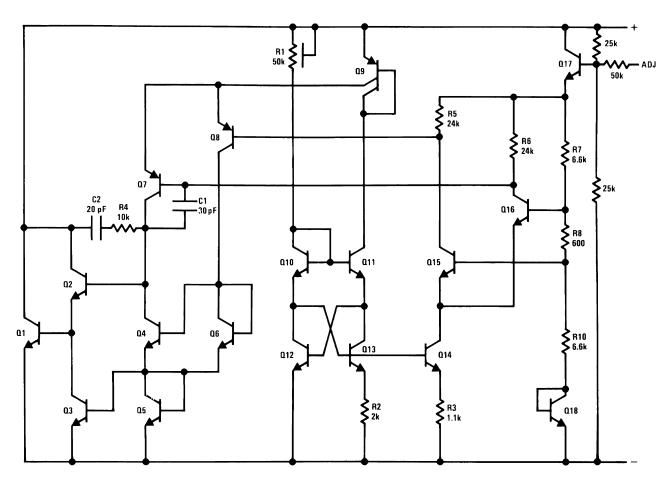


Typical Applications (Continued)

10V Buffered Reference 12V ≤ V_{IN} ≤ 36V 20k 1% 20k 1% 10k 1% 100 pF

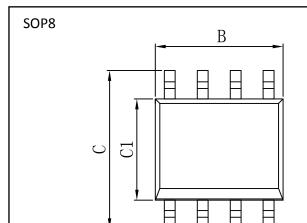


Schematic Diagram



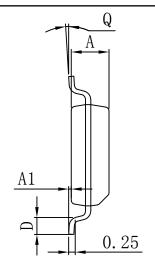


PACKAGE

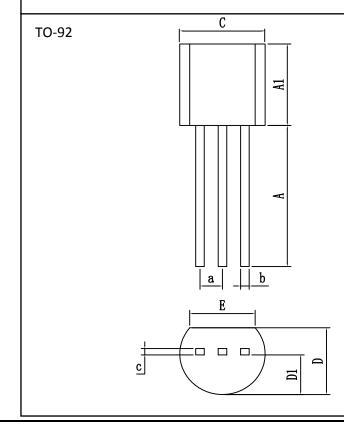


a

b



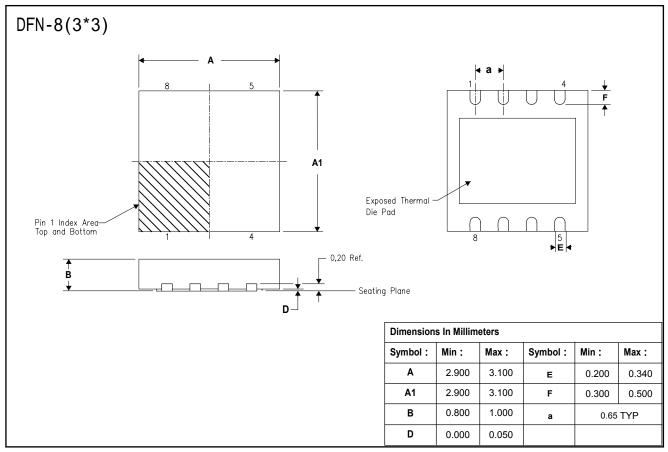
Dimensions In Millimeters						
Symbol:	Min :	Max:	Symbol :	Min:	Max:	
Α	1.225	1.570	D	0.400	0.950	
A1	0.100	0.250	Q	0°	8°	
В	4.800	5.100	а	0.420 TYP		
С	5.800	6.250	b	1.270 TYP		
C1	3.800	4.000				



Dimensions In Millimeters					
Symbol :	Min:	Max:	Symbol :	Min:	Max:
Α	11.200	12.700	E	3.430	3.830
A1	4.320	5.340	а	1.270 TYP	
С	4.440	5.210	b	0.485 TYP	
D	3.170	4.190	С	0.380 TYP	
D1	2.030	2.670			



PACKAGE



9



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